# NSN 5962-01-333-3434

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# Body Length: 1.290 inches Body Width:

Between 0.500 inches and 0.610 inches

## **Body Height:**

Between 0.150 inches and 0.210 inches

## **Maximum Power Dissipation Rating:**

1.4 watts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

6610-01-089-1018 computer, air

#### **Features Provided:**

Hermetically sealed and burn in and programmable and w/active pull-up and w/enable

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

# Output Logic Form:

Transistor-transistor logic

#### Input Circuit Pattern:

14 input

#### **Case Outline Source And Designator:**

D-3 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

90.00 nanoseconds propagation delay time, low to high level output and 90.00 nanoseconds propagation delay time, high to low level

output

#### Memory Device Type:

Rom

#### **Memory Capacity:**

Unknown

### **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### Terminal Type And Quantity:

24 printed circuit

#### Shelf Life:

N/a

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Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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